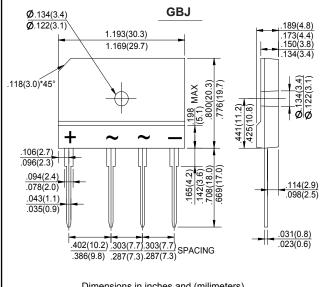


GBJ25005 THRU GBJ2510

SILICON BRIDGE RECTIFIERS

Reverse Voltage - 50 to 1000 Volts Forward Current - 25.0 Amperes



FEATURES

- Rating to 1000V PRV
- Ideal for printed circuit board
- · Low forward voltage drop, high current capability
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- The plastic material has U/L flammability classification 94V-0

Dimensions in inches and	(minimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

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TWGMC Catalog Number	SYMBOLS	GBJ 25005	GBJ 2501	GBJ 2502	GBJ 2504	GBJ 2506	GBJ 2508	GBJ 2510	UNITS
Maximum repetitive peak reverse voltage	Vrrm	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	Vrms	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	Vdc	50	100	200	400	600	800	1000	VOLTS
Maximum Average Forward (with heatsink Note 2) Rectified Current @ Tc =100°C (without heatsink)		25.0 4.2							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	Ifsm	350							Amps
Maximum instantaneous forward voltage drop per birdge element at 12.5A	Vf	1.0							Volts
Maximum DC reverse current TJ=25°C	IR 10								μA
at rated DC blocking voltage TJ=125°C	IR	0.5							mA
It Rating for Fusing (t<8.3ms)	l ² t	508						A ² s	
Typical Junction Capacitance (Note 1)	Сл	85						pF	
Typical Thermal Resistance (Note 2)	Rejc	0.6						°C/W	
Operating junction temperature range	TJ	-55 to +150						°C	
storage temperature range	Тѕтс	-55 to +150						°C	

NOTES: 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2.Device mounted on 75mm*75mm*1.6mm Cu plate heatsink.

3.The typical data above is for reference only(典型值仅供参考).

